NSN 5961-01-356-4296

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-356-4296 **Inclosure Material:** Ceramic or plastic **Overall Length:** Between 0.815 inches and 0.835 inches **Terminal Length:** Between 0.500 inches and 0.750 inches **Overall Height:** Between 0.240 inches and 0.270 inches **Overall Width:** Between 0.685 inches and 0.695 inches **End Application:** Aircraft, hercules c-130 **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Burn in and electrostatic sensitive **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 150.0 reverse voltage, peak all semiconductor **Current Rating Per Characteristic:** 16.00 amperes forward current, average absolute all semiconductor device diode and 150.00 amperes forward current, average preset all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** All semiconductor device diode junction pattern arrangement: pn; weapon system essential **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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